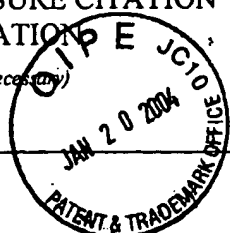


Form PTO-1449 INFORMATION DISCLOSURE CITATION IN AN APPLICATION <i>(Use several sheets if necessary)</i>	Docket Number 559502000800	Application Number 10/730,190
	Applicant Masayuki EHIRO et al.	
	Filing Date December 4, 2003	Group Art Unit Not Yet Assigned
	Mailing Date January 13, 2004	



U.S. PATENT DOCUMENTS

Examiner Initials	Ref. No.	Date	Document No.	Name	Class	Subclass	Filing Date If Appropriate

FOREIGN PATENT DOCUMENTS

Examiner Initials	Ref. No.	Date	Document No.	Country	Class	Subclass	Translation YES NO
DL	1.	01/29/1993	JP 5-21740	Japan			Abstract
DL	2.	07/19/2002	JP 2002-203392	Japan			Abstract

OTHER DOCUMENTS

(including author, title, Date, Pertinent Pages, Etc.)

Examiner Initials	Ref. No.	Title
DL	3.	Liu, S. Q. et al. (2001). "A New Concept for Non-Volatile Memory: The Electric-Pulse Induced Resistive Change Effect in Colossal Magnetoresistive Thin Films," Non-Volatile Memory Technology Symposium Proceedings pp. 1-7, includes 32 supplemental presentation slides.

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